

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	5132	(insulat\$4 same substrate) and transistor and (groove near9 (isolat\$3 or insulat\$4))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/13 15:49
L2	2820	(silicon near5 (isolat\$4 or insulator)) same layer and emitter same base same collector	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/13 15:49
L3	90795	interconnect\$4 same wir\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/13 15:49
L4	28	L1 and L2 and L3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/13 15:49
L5	982	(island or (transistor adj5 region))same groov\$3 same (layer or substrate or layout)same (form\$4 near9 region)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/13 15:49
L6	6	L4 and L5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/13 15:49
L7	40	Tamaki near5 Yoichi	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/13 15:53
L8	2	"6,662,344".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/13 15:56
L9	4	emitter same parallel and i6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/13 15:58